Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S2	4	(("20010006827") or ("20020011205")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/17 16:17
S3	722	(438/29).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/16 10:04
S4	0	S3 and ((mov\$3 reciprocat\$3) same ((substrate semiconduct\$3) and (evaporat\$3 near5 (souce cell))))	US-PGPUB; 'USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 10:09
S5	141	S3 and ((mov\$3 reciprocat\$3) same (substrate semiconduct\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:50
S6	99	S3 and (EL electro near3 luminescence)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 16:06
S7	0	("2004/0077113").URPN.	USPAT	OR	ON	2005/08/16 10:19
S8	0	("2004/0009303").URPN.	USPAT	OR	ON	2005/08/16 10:20

,		*	<u> </u>	т		
S9	90	("20010001050"   "20020041302"   "20020041926"   "20020136823"   "20020155215"   "20030054186"   "4356429"   "4530750"   "4539507"   "4720432"   "4769292"   "4885211"   "4950950"   "4975338"   "5003221"   "5047687"   "5073446"   "5107175"   "5124204"   "5151629"   "5189405"   "5217700"   "5247190"   "5270267"   "5294869"   "5294870"   "5338364"   "5399502"   "5438241"   "5482896"   "5496597"   "5530269"   "5552668"   "5641991"   "5643826"   "5674304"   "5680165"   "5680185"   "5683956"   "5747930"   "5757126"   "5771562"   "5811177"   "5824374"   "5839456"   "5923962"   "5929487"   "5923962"   "5929487"   "5952708"   "5952778"   "5962962"   "5990542"   "6028325"   "6057647"   "6097459"   "6100954"   "6115090"   "6129602"   "6146225"   "6150187"   "6150668"   "6169293"   "6194837"   "6251712"   "6268631"   "6278132"   "6268631"   "6278132"   "6281634"   "6283578"   "6316810"   "6413645"   "6441468"   "6451636"   "6441468"   "6451636"   "6461885"   "6575800"   "6619334"   "6667188").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/16 12:58
S10	0	("6810919").URPN.	USPAT	OR	ON	2005/08/16 12:58
S11	4	("20020041302"   "6451636"   "6619334"   "6667188").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/16 12:59
S12	287	(438/69).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/16 14:06
S13	113	S12 and (apparatus reactor same (vapor near3 deposition))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2005/08/16 16:05

S14	170	(438/82).CCLS.	US-PGPUB;	OR	OFF	2005/08/16 14:50
			USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB			
S15	4	("2001/0006827").URPN.	USPAT	OR	ON	2005/08/16 15:41
S16	4	("2001/0006827").URPN.	USPAT	OR	ON	2005/08/16 15:41
S17	567	(438/99).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/16 16:04
S18	567	(438/99).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/16 16:04
S19	182	S18 and (vapor near3 deposition)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:18
S20	104	S18 and (EL (electro near3 luminescence))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:18
S21	1638	(438/680).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/17 16:17
S22	771	S21 and (vapor near3 deposition)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:54
S23	7	S22 and (EL (electro near3 luminescence))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:54

•						
S24	8	S21 and (EL (electro near3 luminescence))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:25
S25	3	("2001093667").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/17 16:31
S26	1364	S21 and ((uniform even flat) near5 surface film )	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:55
S27	670	S22 and ((uniform even flat) near5 surface film )	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:32
S28	2	S22 and ((mov\$3 reciprocat\$3) near5 ((substrate semiconduct\$3) and (source cell evaporat\$3)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:56
S29	768634	EL (electro near3 luminescence)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:54
S30	6901	S29 and (vapor near3 deposition)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:54
S31	2550	S30 and ((uniform even flat) near5 (surface film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:55

•						
S32	14	S31 and ((mov\$3 reciprocat\$3) near5 ((substrate semiconduct\$3) and (evaporat\$3 near4 source)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 17:02
S33	389	S31 and ((mov\$3 reciprocat\$3) near5 (substrate semiconduct\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 18:25
S34	14	S33 and ((mov\$3 reciprocat\$3) near5 (evaporat\$3 near4 source))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 17:22
S35	24	S31 and ((mov\$3 reciprocat\$3 direction) near5 (evaporat\$3 near4 source))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 17:23
S36	23	S35 and ((mov\$3 reciprocat\$3 direction) near5 (substrate semiconduct\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 17:24
S37	22	S35 and ((mov\$3 reciprocat\$3 direction) near3 (substrate semiconduct\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 17:24
S38	0	("2004/0031442").URPN.	USPAT	OR	ON	2005/08/18 12:41
S39	18	(("2435997") or ("3931490") or ("4951601") or ("6049167") or ("6132280") or ("20010006827") or ("20020197418")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/18 12:49
S40	2	("20040031442").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/18 12:54

S41	4	(("20020187265") or ("20020197418")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/18 12:59
S42	2	("20040040504").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/18 12:59
S43	0	("2004/0009303").URPN.	USPAT	OR	ON	2005/08/18 13:15